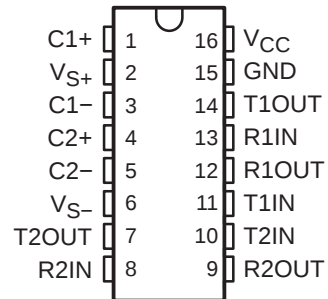


MAX232, MAX232I DUAL EIA-232 DRIVERS/RECEIVERS

SLLS047L – FEBRUARY 1989 – REVISED MARCH 2004

- Meets or Exceeds TIA/EIA-232-F and ITU Recommendation V.28
- Operates From a Single 5-V Power Supply With 1.0- μ F Charge-Pump Capacitors
- Operates Up To 120 kbit/s
- Two Drivers and Two Receivers
- ± 30 -V Input Levels
- Low Supply Current . . . 8 mA Typical
- ESD Protection Exceeds JESD 22 – 2000-V Human-Body Model (A114-A)
- Upgrade With Improved ESD (15-kV HBM) and 0.1- μ F Charge-Pump Capacitors is Available With the MAX202
- Applications
 - TIA/EIA-232-F, Battery-Powered Systems, Terminals, Modems, and Computers

MAX232 . . . D, DW, N, OR NS PACKAGE
MAX232I . . . D, DW, OR N PACKAGE
(TOP VIEW)



description/ordering information

The MAX232 is a dual driver/receiver that includes a capacitive voltage generator to supply TIA/EIA-232-F voltage levels from a single 5-V supply. Each receiver converts TIA/EIA-232-F inputs to 5-V TTL/CMOS levels. These receivers have a typical threshold of 1.3 V, a typical hysteresis of 0.5 V, and can accept ± 30 -V inputs. Each driver converts TTL/CMOS input levels into TIA/EIA-232-F levels. The driver, receiver, and voltage-generator functions are available as cells in the Texas Instruments LinASIC™ library.

ORDERING INFORMATION

T _A	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	PDIP (N)	Tube of 25	MAX232N	MAX232N
	SOIC (D)	Tube of 40	MAX232D	MAX232
		Reel of 2500	MAX232DR	
	SOIC (DW)	Tube of 40	MAX232DW	MAX232
		Reel of 2000	MAX232DWR	
-40°C to 85°C	SOP (NS)	Reel of 2000	MAX232NSR	MAX232
	PDIP (N)	Tube of 25	MAX232IN	MAX232IN
	SOIC (D)	Tube of 40	MAX232ID	MAX232I
		Reel of 2500	MAX232IDR	
	SOIC (DW)	Tube of 40	MAX232IDW	MAX232I
		Reel of 2000	MAX232IDWR	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinASIC is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2004, Texas Instruments Incorporated

MAX232, MAX232I
DUAL EIA-232 DRIVERS/RECEIVERS

SLLS047L – FEBRUARY 1989 – REVISED MARCH 2004

Function Tables

EACH DRIVER

INPUT TIN	OUTPUT TOUT
L	H
H	L

H = high level, L = low level

EACH RECEIVER

INPUT RIN	OUTPUT ROUT
L	H
H	L

H = high level, L = low level

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Input supply voltage range, V_{CC} (see Note 1)	–0.3 V to 6 V
Positive output supply voltage range, V_{S+}	$V_{CC} - 0.3$ V to 15 V
Negative output supply voltage range, V_{S-}	–0.3 V to –15 V
Input voltage range, V_I : Driver	–0.3 V to $V_{CC} + 0.3$ V
Receiver	± 30 V
Output voltage range, V_O : T1OUT, T2OUT	$V_{S-} - 0.3$ V to $V_{S+} + 0.3$ V
R1OUT, R2OUT	–0.3 V to $V_{CC} + 0.3$ V
Short-circuit duration: T1OUT, T2OUT	Unlimited
Package thermal impedance, θ_{JA} (see Notes 2 and 3): D package	73°C/W
DW package	57°C/W
N package	67°C/W
NS package	64°C/W
Operating virtual junction temperature, T_J	150°C
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to network GND.
2. Maximum power dissipation is a function of $T_J(\text{max})$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	4.5	5	5.5	V
V_{IH}	High-level input voltage (T1IN, T2IN)	2			V
V_{IL}	Low-level input voltage (T1IN, T2IN)			0.8	V
R1IN, R2IN	Receiver input voltage			± 30	V
T_A	Operating free-air temperature	MAX232	0	70	°C
		MAX232I	–40	85	

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

PARAMETER	TEST CONDITIONS	MIN	TYP [‡]	MAX	UNIT
I_{CC} Supply current	$V_{CC} = 5.5$ V, All outputs open, $T_A = 25^\circ\text{C}$		8	10	mA

[‡] All typical values are at $V_{CC} = 5$ V and $T_A = 25^\circ\text{C}$.

NOTE 4: Test conditions are C1–C4 = 1 μF at $V_{CC} = 5$ V ± 0.5 V.

MAX232, MAX232I

DUAL EIA-232 DRIVERS/RECEIVERS

SLLS047L – FEBRUARY 1989 – REVISED MARCH 2004

DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature range (see Note 4)

PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V _{OH}	High-level output voltage	T1OUT, T2OUT R _L = 3 kΩ to GND	5	7		V
V _{OL}	Low-level output voltage [‡]	T1OUT, T2OUT R _L = 3 kΩ to GND		-7	-5	V
r _o	Output resistance	T1OUT, T2OUT V _{S+} = V _{S-} = 0, V _O = ±2 V	300			Ω
I _{OS} [§]	Short-circuit output current	T1OUT, T2OUT V _{CC} = 5.5 V, V _O = 0		±10		mA
I _{IS}	Short-circuit input current	T1IN, T2IN V _I = 0			200	μA

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C.

[‡] The algebraic convention, in which the least-positive (most negative) value is designated minimum, is used in this data sheet for logic voltage levels only.

[§] Not more than one output should be shorted at a time.

NOTE 4: Test conditions are C1–C4 = 1 μF at V_{CC} = 5 V ± 0.5 V.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see Note 4)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Driver slew rate	R _L = 3 kΩ to 7 kΩ, See Figure 2			30	V/μs
SR(t)	Driver transition region slew rate	See Figure 3		3		V/μs
	Data rate	One TOUT switching		120		kbit/s

NOTE 4: Test conditions are C1–C4 = 1 μF at V_{CC} = 5 V ± 0.5 V.

RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature range (see Note 4)

PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V _{OH}	High-level output voltage	R1OUT, R2OUT I _{OH} = -1 mA	3.5			V
V _{OL}	Low-level output voltage [‡]	R1OUT, R2OUT I _{OL} = 3.2 mA			0.4	V
V _{IT+}	Receiver positive-going input threshold voltage	R1IN, R2IN V _{CC} = 5 V, T _A = 25°C		1.7	2.4	V
V _{IT-}	Receiver negative-going input threshold voltage	R1IN, R2IN V _{CC} = 5 V, T _A = 25°C	0.8	1.2		V
V _{hys}	Input hysteresis voltage	R1IN, R2IN V _{CC} = 5 V	0.2	0.5	1	V
r _i	Receiver input resistance	R1IN, R2IN V _{CC} = 5, T _A = 25°C	3	5	7	kΩ

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C.

[‡] The algebraic convention, in which the least-positive (most negative) value is designated minimum, is used in this data sheet for logic voltage levels only.

NOTE 4: Test conditions are C1–C4 = 1 μF at V_{CC} = 5 V ± 0.5 V.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see Note 4 and Figure 1)

PARAMETER		TYP	UNIT
t _{PLH(R)}	Receiver propagation delay time, low- to high-level output	500	ns
t _{PHL(R)}	Receiver propagation delay time, high- to low-level output	500	ns

NOTE 4: Test conditions are C1–C4 = 1 μF at V_{CC} = 5 V ± 0.5 V.



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MAX232D	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX232DR	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX232DW	ACTIVE	SOIC	DW	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX232DWR	ACTIVE	SOIC	DW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX232ID	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX232IDR	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX232IDW	ACTIVE	SOIC	DW	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX232IDWR	ACTIVE	SOIC	DW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX232IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
MAX232N	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
MAX232NSR	ACTIVE	SO	NS	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.